SIEMENS

Data sheet 3RF2330-1AA14



Solid-state contactor 1-phase 3RF2 AC 51 / 30 A / 40 $^{\circ}\text{C}$ 48-460 V / 24 V AC/DC screw terminal

product brand name	SIRIUS
product designation	solid-state contactor
design of the product	single-phase
product type designation	3RF23
manufacturer's article number	
_1 of the accessories that can be ordered	3RF2900-3PA88
_3 of the accessories that can be ordered	3RF2900-0EA18
_4 of the accessories that can be ordered	3RF2950-0GA16
product designation	
_1 of the accessories that can be ordered	terminal cover
_3 of the accessories that can be ordered	converter
_4 of the accessories that can be ordered	load monitoring
General technical data	
product function	zero-point switching
power loss [W] for rated value of the current	
 at AC in hot operating state 	33 W
 at AC in hot operating state per pole 	33 W
without load current share typical	0.5 W
insulation voltage rated value	600 V
degree of pollution	3
type of voltage	
 of the operating voltage 	AC
of the control supply voltage	AC/DC
surge voltage resistance of main circuit rated value	6 kV
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to EN 61346-2	Q
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	05/28/2009
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0
type of voltage of the operating voltage	AC
operating voltage	
• at AC	
— at 50 Hz rated value	48 460 V
— at 60 Hz rated value	48 460 V
operating frequency rated value	50 60 Hz
operating range relative to the operating voltage at AC	

. =	40 70014
• at 50 Hz	40 506 V
• at 60 Hz	40 506 V
operational current	00.4
• at AC-51 rated value	30 A
• at AC-51 according to IEC 60947-4-3	22 A
according to UL 508 rated value	27 A
operational current minimum	500 mA
rate of voltage rise at the thyristor for main contacts maximum permissible	1 000 V/μs
blocking voltage at the thyristor for main contacts maximum permissible	1 200 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	600 A
I2t value maximum	1 800 A²-s
Control circuit/ Control	
type of voltage of the control supply voltage	AC/DC
control supply voltage 1 at AC	
● at 50 Hz	24 24 V
• at 60 Hz	24 24 V
control supply voltage frequency	
• 1 rated value	50 Hz
2 rated value	60 Hz
control supply voltage 1	
at DC rated value	30 V
• at DC	15 24 V
control supply voltage at AC	
 at 50 Hz full-scale value for signal<0> recognition 	5 V
• at 60 Hz full-scale value for signal<0> recognition	5 V
control supply voltage	
 at AC initial value for signal <1> detection 	14 V
 at DC initial value for signal <1> detection 	15 V
 at DC full-scale value for signal<0> recognition 	5 V
symmetrical line frequency tolerance	5 Hz
control current at minimum control supply voltage	
• at AC	2 mA
control current at AC rated value	15 mA
control current at DC rated value	20 mA
ON-delay time	1 ms; additionally max. one half-wave
OFF-delay time	15 ms; additionally max. one half-wave
Auxiliary circuit	
number of NC contacts for auxiliary contacts	0
number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method	screw fixing and snap-on mounting on standard mounting rail 35 mm according
 side-by-side mounting 	to IEC 60715 Yes
design of the thread of the screw for securing the	M4
equipment	
height	95 mm
width	45 mm
depth	135.5 mm
Connections/ Terminals	
product component removable terminal for auxiliary and control circuit	Yes
type of electrical connection	
for main current circuit	screw-type terminals
for auxiliary and control circuit	screw-type terminals
type of connectable conductor cross-sections	"
• for main contacts	
— solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
JOHA	

finally atomical advicts are and	0. (4. 0.5 mags) 0. (0.5 0) 4. 40
— finely stranded with core end processing	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm²
for AWG cables for main contacts	2x (14 10)
connectable conductor cross-section for main contacts	
solid or stranded	1.5 6 mm²
finely stranded with core end processing	1 10 mm²
type of connectable conductor cross-sections	
 for auxiliary and control contacts 	
— solid	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded with core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded without core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 for AWG cables for auxiliary and control contacts 	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for main contacts	10 14
tightening torque	
 for main contacts with screw-type terminals 	2 2.5 N·m
 for auxiliary and control contacts with screw-type terminals 	0.5 0.6 N·m
tightening torque [lbf·in]	
• for main contacts with screw-type terminals	18 22 lbf·in
 for auxiliary and control contacts with screw-type terminals 	4.5 5.3 lbf·in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	
• for main contacts	7 mm
for auxiliary and control contacts	7 mm
Safety related data	
protection class IP on the front according to IEC 60529	IP20
touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front
Ambient conditions	
installation altitude at height above sea level maximum	1 000 m
ampient temperature	
ambient temperature • during operation	-25 +60 °C
during operation	-25 +60 °C -55 +80 °C
during operation during storage	
during operation during storage Electromagnetic compatibility	
during operation during storage Electromagnetic compatibility conducted interference	-55 +80 °C
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4	-55 +80 °C 2 kV / 5 kHz behavior criterion 2
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at cylindrical design usable of back-up R fuse link for semiconductor protection at NH	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at cylindrical design usable of back-up R fuse link for semiconductor protection at NH design usable of back-up R fuse link for semiconductor protection at NH design usable of back-up R fuse link for semiconductor protection at NH design usable of back-up R fuse link for semiconductor protection at NH design usable of back-up R fuse link for semiconductor protection at NH design usable of back-up R fuse link for semiconductor protection at	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at cylindrical design usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at cylindrical design usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450
during operation during storage Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at cylindrical design usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 12 x 58 mm usable	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450

	<u>relays</u>
• at cylindrical design 14 x 51 mm usable	3NW6105-1; These fuses have a smaller rated current than the semiconductor relays
• at cylindrical design 22 x 58 mm usable	3NW6205-1; These fuses have a smaller rated current than the semiconductor relays
manufacturer's article number	
• of DIAZED fuse usable	5SB2711: These fuses have a smaller rated current than the semiconductor relays
of NEOZED fuse usable	5SE2320: These fuses have a smaller rated current than the semiconductor relays

Certificates/ approvals

General Product Approval

EMC

Declaration of Conformity



Confirmation









Declaration of Conformity

Test Certificates

other

Railway



Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Vibration and Shock

Further information

Siemens has decided to exit the Russian market (see here).

https://press.siemens.com/global/en/pressrelease/siemens-wind-down-russian-business

Siemens is working on the renewal of the current EAC certificates.

Please contact your local Siemens office on the status of validity of the EAC certification if you intend to import or offer to supply these products to an EAC relevant market (other than the sanctioned EAEU member states Russia or Belarus).

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2330-1AA14

Cax online generator

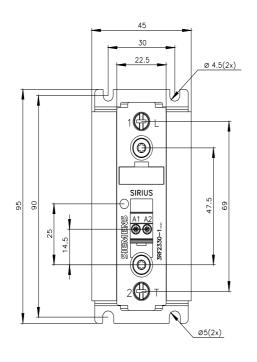
 $\underline{\text{http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en\&mlfb=3RF2330-1AA14}}$

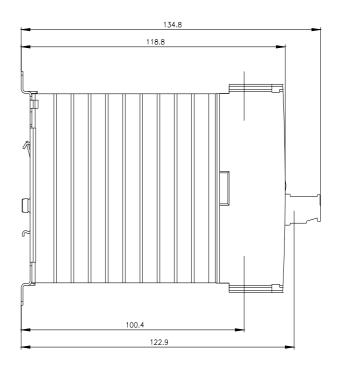
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

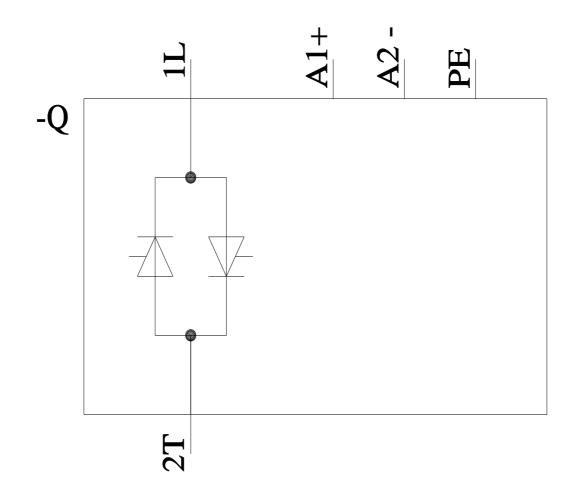
https://support.industry.siemens.com/cs/ww/en/ps/3RF2330-1AA14

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3RF2330-1AA14&lang=en







last modified: 10/6/2023 🖸

